Application Note



UV-C Sensor (Peak Responsivity: 265nm, Detection Range: 220nm~280nm)

UV-C sensor is Aluminium Gallium Nitride-based materials with Schottky Photodiode. UV-C sensors detect a UVC wavelength(220nm~280nm) and used in sterilization lamp monitoring

- The durability of the package should be good in order to detect UVC wavelength.

 According to the package type, UV sensors can be used selectively with applications.

Package Type	Picture of products	Viewing angle(*)	Applications	
SMD 3535		150	Compact equipment, mobile phone, wide Viewing angle sensing	
TO-46	40	60		
TO-39	0	60	Metal material of TO-CAN type and general applications	
ТО-5	=60	100		

Fig. 1 Package Type

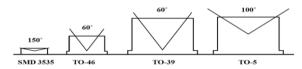


Fig. 2 Viewing angle in accordance with the package type

2. Type of UV chips

The larger the chip size the higher output value(Photo current).

Output Value	Standard Chip	Large Chip	Ultra Large Chip	
Output Value	Standard Chip	Large Chip	Olda Large Chip	
Picture of UV chip				
Chip Size (mm')	0.4 × 0.4	1.4 × 1.4	3.4 × 3.4	
Active area (mm')	0.076	1.536	6.894	
Photo current	34nA	0.55µA	3.25µA	
Photo current	※ Optical source : 1mW/cm², 254nm UVC Lamp			

Fig. 3 Type of UV chips

3. Dark current

The small electric current that flows through UV sensor when no photons are entering the device.

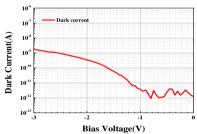


Fig. 4 Dark current of UVC sensor (Log scale)

Parameter	Max.	Unit	Test Conditions
Dark current	1	nA	Vr = 0.1V

4. Responsivity

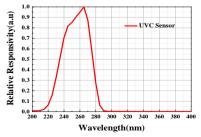


Fig. 5 Relative Responsivity

Parameter	UVC Sensor
Peak Wavelength(nm)	265
Spectral Detection Range(nm)	220~280
Material of window	Quartz glass

5. Classification by output value

- UV Sensor output values have two ways, as current or voltage for the UV response.
- $\,$ GH series are voltage output component, and the Op-Amp is mounted therein.

Output value	Current Output		Voltage Output		age Output	
Model	GD series (SMD, TO-CAN PKG)			GH series		
Feature	(Current C	Output	Amplified Voltage Output		
Direction of electrode	SMD PKG	11	3,5 		foc)	
and Pin information	TO-CAN PKG	#2.510.0 #1.110.00	Anode	(0	GND)	5.1±0.2 8.1±0.20 9.1±0.20
Structure	+		= 0		+)+((())=
	Chip	Case	UV sensor of current output	Chip	Case	PCB UV sensor of voltage output

Fig. 6 Classification by output value

6. Application circuit

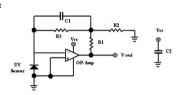


Fig. 7 Application circuit

Part No.	Model and Value	Function	Remark	
UV Sensor	UVC Sensor	UV Sensing	Anode connects to ground	
Op-Amp	MCP6241 (Vcc = 1.8 ~5.5V) LMC6081 (Vcc = 4.5 ~ 15V) OPA237 (Vcc = 2.7 ~36V)	Amplification	Input Offset Current < 1nA	
Capacitor (C1)	1nA	Decreasing input noise	Decrease the value for fast response (e.g. 100pF) Increase the value for reducing errors (e.g. 10nF)	
Capacitor (C2) 0.1μF		Stabilization of power	Internal voltage of capacitor > Vcc	
Resister (R1, 2, 3)	Resister (R1, 2, 3) R1=0Ω, R2=X, R3=7.5MΩ		Gain: R3 × (1+R1/R2)	

7 Application of the UV lamps

7. Application				
Internal pressure Type of lamp		Applications	Available product	
Low	Cleaning Lamp	Surface cleaning (LCD, PDP, OLED,		
Pressure UV	cicuming cump	Optic glass, Lead frame, acrylic)	All UVC Sensors	
Lamp	Organic matter decomposition Lamp	decomposing TOC and COD in water		
(Under 1kg/cm')	sterilization UV Lamp	Sterilizing water and air		
Middle	Medium Pressure Mercury Lamp	Coating, Ink curing		
Pressure UV	Iron Iodide Metal Halide Lamp	Coating, Ink and adhesive curing		
Lamp	Ga Iodide Metal Halide Lamp	Film processing,	All UVC Sensors (Using Diffuser)	
(2~3kg/cm²)	Ga todide iwetai Halide Lallip	Shadow mask, etching		
High Pressure UV Lamp Short Arc High Pressure (Under Mercury Xe Lamo			(Osing Dinuser)	
		Spot UV analysor, UV stepper		
5~10 kg/cm')	,			

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	OUTPUT	Model No.	Package Type	Chip Size	The minimum detectable quantity of light	Output Value**
ı		GUVC-S10GD	SMD 3535	0.4 × 0.4		39nA
	Current	GUVC-T10GD	TO-46	0.4 × 0.4	$0.1 \mu \text{W/cm}^2$	34nA
		GUVC-T11GD*	TO-46	0.4 × 0.4		
ı		GUVC-T10GD-L	TO-46	1.4 × 1.4	0.01µW/m²	0.55µA
ı		GUVC-T20GD-U	TO-39	3.4 × 3.4	$0.001 \mu \text{W/cm}^{\circ}$	3.25µA
ı	Voltage	GUVC-T21GH	TO-5	0.4 × 0.4	0.1µW/cm²	0.355V

- * GUVC-T11GD and GUVC-T10GD are same package type. But direction of electrode is opposite.
- ** Optical source power: 1mW/m², 254nm UVC Lamp
- *** The maximum detectable quantity of light: 100mW/cm² (Please contact us when optical source power is over 100mW/cm².)

- 1) ESD (Electro-Static Discharge)
- ESD and surge voltage can cause damage to UV sensor.
- It is recommended that using antistatic wrist strap or antistatic gloves when handing the UV sensors.

- If moisture is absorbed into the inside of the device, occur expansion and vaporization during the soldering process. This phenomenon can give damaged to optical properties and appearance of UV sensors.
- UV sensors are packaged in aluminium moisture barrier bags and put in silica gel.

- If not insulated the cap of TO-CAN package type, it's cause malfunction to the device.
- Storage conditions : Temperature 5~30°C, please keeping the condition of moisture is less than RH 65%.
- Soldering Conditions : Max. 260°C (Temperature), Max. 10sec. (Time)